

Magnetotransport of the low-carrier density one-dimensional $S = 1/2$ antiferromagnet Yb_4As_3

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Abstract. The transport properties of the semimetallic quasi-one-dimensional $S = 1/2$ antiferromagnet Yb_4As_3 have been studied by performing low-temperature ($T \geq 0.02$ K) and high magnetic-field ($B \leq 60$ T) measurements of the electrical resistivity $\rho(T, B)$. For $T \gtrsim 2$ K a ‘heavy-fermion’-like behavior $\Delta\rho(T) = AT^2$ with huge and nearly field-independent coefficient $A \approx 3 \mu\Omega \text{ cm/K}^2$ is observed, whereas at lower temperatures $\rho(T)$ deviates from this behavior and slightly increases to the lowest T . In $B > 0$ and $T \lesssim 6$ K the resistivity shows an anomalous magnetic-history dependence together with an unusual relaxation behavior. In the isothermal resistivity Shubnikov–de Haas (SdH) oscillations, arising from a low-density system of mobile As-4*p* holes, with a frequency of 25 T have been recorded. From the T - and B -dependence of the SdH oscillations an effective carrier mass of $(0.275 \pm 0.005)m_0$ and a charge-carrier mean-free path of 215 Å are determined. Furthermore, in $B \geq 15$ T, the system is near the quantum limit and spin-splitting effects are observed.

Keywords. $S = 1/2$ antiferromagnet Yb_4As_3 ; magnetotransport; isothermal resistivity; heavy fermion; Shubnikov–de Haas oscillations.

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1. Introduction

The low-carrier density system Yb_4As_3 has recently attracted the interest of many researchers due to its quantum-spin chains. At room temperature, Yb_4As_3 , crystallizing in the cubic anti- Th_3P_4 structure, is an intermediate-valent metal with an average valence ratio $\text{Yb}^{3+}/\text{Yb}^{2+} = 1 : 3$ [1]. The Yb ions are located on the four interpenetrating families of the cubic space diagonals. At $T_{\text{CO}} \approx 295$ K a charge-order (CO) transition, driven by intersite Coulomb repulsion and a deformation potential coupling to the lattice, takes place which causes the smaller Yb^{3+} ions to order along *one* of the cubic space diagonals. The trigonal lattice distortion accompanying the CO transition usually results in the formation of a polydomain low- T structure. A preferential orientation of the domains can be induced by the application of a small uniaxial pressure along one space diagonal prior to cooling through T_{CO} . The crystal-electric field (CEF) ground state of the Yb^{3+} ions can be described by an

effective $S = 1/2$ doublet [2]. The Yb^{3+} chains are well-separated from each other by non-magnetic Yb^{2+} and As^{3-} ions. The low-energy excitations of these $S = 1/2$ chains have been found using inelastic neutron scattering (INS) experiments [2] to agree well with the des Cloizeaux–Pearson ‘magnon’ spectrum (lower bound of the two-spinon continuum) of a $S = 1/2$ antiferromagnetic (AF) Heisenberg chain with a nearest-neighbor AF coupling $|J| = 2.2$ meV (corresponding to $k_B \cdot 25.5$ K). The large ‘heavy-fermion’ (‘HF’) like in- T linear contribution to the specific heat, $C(T)/T = \gamma$ with $\gamma = 0.2$ J/K² mol [1], is in excellent agreement with the expected ‘magnon’ contribution. The application of magnetic fields B with a finite component perpendicular to the spin chains leads to the opening of a gap $\Delta(B)$ in the low-energy excitation spectrum and ‘soliton’-type anomalies, which were first observed in specific heat [3], thermal expansion and thermal conductivity measurements [4]. The spin gap was later directly confirmed using inelastic neutron diffraction at the boundary of the AF Brillouin zone [5]. Below 12 T, a $\Delta(B) \sim B^{2/3}$ dependence was observed [6] which can be explained in the frame of the quantum sine-Gordon model taking into account an alternating Dzyaloshinskii–Moriya (DM) interaction [7]. Furthermore, at very low- T a spin-glass (SG) transition at $T_{\text{SG}} = 0.15$ K arises due to weak ferromagnetic interchain coupling and disorder [6,8]. A detailed review on the magnetic properties of Yb_4As_3 is given in [9,10], and most recent results concerning the SG properties can be found in [6]. Here, we concentrate on the unusual electrical-transport properties of Yb_4As_3 .

The $4f$ electronic state in the CO state, which is slightly incomplete, can be expressed as $\text{Yb}^{3+}\text{Yb}_3^{2+}\text{As}_3^{3-}$, where the smaller Yb^{3+} ions are arranged predominantly on the short chain parallel to, e.g., the former cubic $\langle 111 \rangle$ direction. The low- T Hall coefficient R_H is positive, implying a dominant hole conduction. The value of $(eR_H)^{-1} = 7 \times 10^{18}$ cm⁻³ corresponds to a density of only 0.001 per Yb^{3+} ion, if one assumes the presence of only one type of charge carriers [1]. Non-spin-polarized LDA band-structure calculations of the hypothetical LuYb_3As_3 system suggested a semimetallic character of Yb_4As_3 [11]. Antonov *et al* [12] calculated the LSDA + U band structure of Yb_4As_3 for energies close to the Fermi level. The U value was adjusted to $U_{\text{eff}}^{3+} = 9.6$ eV, and the f shell of the Yb^{2+} ions was treated as a core shell. An extremely narrow marginally occupied Yb^{3+} - $4f$ hole band was pinned, via the charge balance between Yb and As, at the top of the As- $4p$ valence band. Thus, the number of As- p holes exactly equals the number of excess Yb- $4f$ electrons in the partially filled $4f$ hole level. Therefore, the Fermi surface consists of (1) a hole pocket of light ($\sim 0.6m_0$) As- $4p$ states centered on the Γ point and (2) an electron pocket centered on the Γ -P symmetry line with a heavy effective mass of about $38m_0$ [12]. The mobility of these heavy $4f$ electrons is almost negligible compared to that of the light As- $4p$ holes.

Most remarkably, the electrical resistivity $\rho(T)$ was reported to follow a T^2 behavior between 2 and 40 K, with a large coefficient $A \approx 0.75$ $\mu\Omega$ cm/K² [1]. The Kadowaki–Woods scaling observed for usual HF metals is fulfilled (within a factor of 2), although the low-carrier concentration excludes the usual Kondo effect to be operating. This article is organized as follows: After giving details concerning experimental techniques in the next section, we address in §3 the yet unexplained ‘HF’ behavior in $\rho(T)$. In §4 we present new results on unusual hysteresis and relaxation which were found for $B > 0$ in the electrical resistivity. A quantitative analysis of Shubnikov–de Haas (SdH) oscillations observed in the isothermal resistivity is given in §5, and the summary is presented in §6.

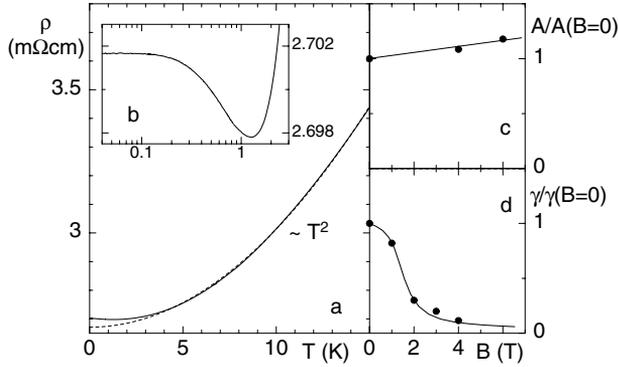


Figure 1. Zero-field electrical resistivity for polydomain Yb_4As_3 , plotted as ρ vs. T (a) and ρ vs. $\log(T/K)$ (inset (b)); as well as field dependence of coefficient A of the $\rho(T, B) = \rho_0(B) + a(B)T^2$ behavior [8] (c) and coefficient of the in- T linear low- T specific heat, $\gamma(B) = C(T, B)/T$ [3] (d), both normalized to their values at $B = 0$.

2. Experimental details

The experiments were performed on rectangular pieces, approximately $(1.8 \times 0.7 \times 0.3) \text{ mm}^3$, of a high-quality single crystal that was grown by a self-flux method as described in [1]. The electrical resistivity $\rho(T, B)$ was measured using the standard four-probe ac-method adapted to a $^3\text{He}/^4\text{He}$ dilution refrigerator with a 19 T superconducting magnet. High-field experiments were performed in Los Alamos High Magnetic Field Laboratory using a short pulse (25 ms) 60 T magnet.

3. ‘Heavy-fermion’ behavior in resistivity

As shown in figure 1a, the resistivity follows a $\rho(T) - \rho_0 = AT^2$ dependence with $A = 3.4 \mu\Omega \text{ cm/K}^2$ down to 4 K. At lower temperatures, $\rho(T)$ deviates from the T^2 dependence, passes through a minimum at 2 K followed by 0.15% increase which saturates below 0.1 K (figure 1b). The increase of the resistivity below about 4 K might be related to spin-disorder scattering above the SG freezing which was observed in ac-susceptibility measurements below 0.15 K [6,8]. Alternatively, it might be ascribed to the dynamic character of the CO state (see below). Compared to the previous measurements by Ochiai *et al* [1], our recent experiments reveal roughly three times higher values both of the residual resistivity ρ_0 and the coefficient A , as well as, a more than two times larger Hall coefficient, corresponding to a carrier concentration $(eR_H)^{-1} = 3 \times 10^{18} \text{ cm}^{-3}$ [9]. The large value of coefficient A increases slightly with magnetic field up to 18 T [8], while the specific heat coefficient γ rapidly decreases, indicating the formation of a spin gap in the ‘magnon’ spectrum [3] (figures 1c and 1d). This observation is in striking conflict with the assignment of the large A coefficient as resulting from the scattering of the light carriers off the ‘magnon’ excitations [12]. We, therefore, propose that in Yb_4As_3 it is the scattering of light and mobile $\text{As-}4p$ holes off the heavy $\text{Yb-}4f$ electrons that leads to HF-type behavior in the resistivity. The band structure should not be affected by magnetic fields of the order

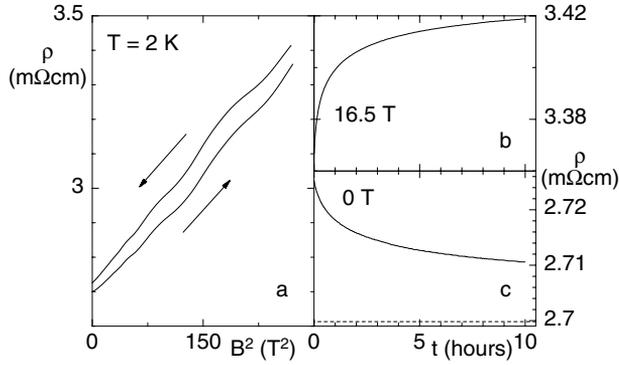


Figure 2. Isothermal electrical resistivity of polydomain Yb_4As_3 at 2 K as ρ vs. B^2 (a) measured with 0.25 T/min. Arrows indicate the magnetic history of the data. The offset is due to relaxation in the resistivity $\rho(t)$ observed at 16.5 T (b) and after driving the field back to 0 T (c). The dotted line in (c) marks the zero-field resistivity at the beginning of the cycle.

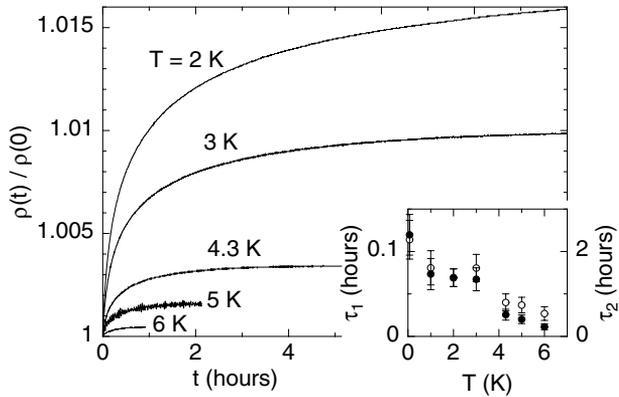


Figure 3. Normalized relaxation $\rho(t)/\rho(0)$ in 16.5 T applied with a rate of 0.25 T/min at different temperatures. The different curves can be approximated to $\rho(t)/\rho(0) = A_1 \exp(-\tau_1/t) + A_2 \exp(-\tau_2/t)$. The inset shows the temperature dependence of the time constants τ_1 (○) and τ_2 (●).

of 10 T [13]. Therefore, the large A coefficient also remains almost constant and does not reflect the field-induced gap in the spin-excitation spectrum.

4. Unusual relaxation behavior when $B > 0$

The isothermal resistivity roughly follows a B^2 behavior (figure 2a), typical for compensated semimetals. The superimposed Shubnikov–de Haas oscillations will be discussed in the subsequent section. A pronounced hysteresis is observed upon increasing and

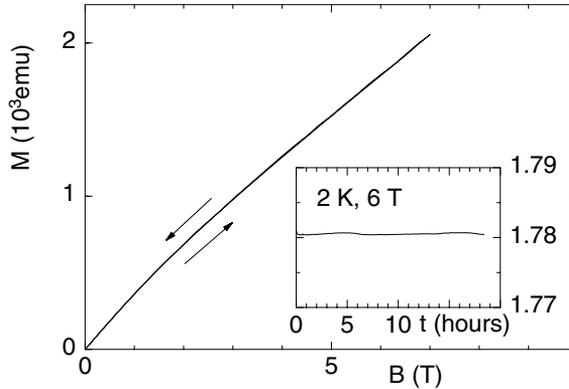


Figure 4. Isothermal dc magnetization M of polydomain Yb_4As_3 for magnetic fields B applied along the cubic $\langle 111 \rangle$ direction at $T = 2$ K, measured with a commercial SQUID magnetometer. The inset shows the time dependence $M(t)$ vs. t at 2 K after the application of magnetic field of 6 T.

decreasing B (figure 2a) as well as upon warming and cooling in $B > 0$ [8]. This effect which has also been observed by Aoki *et al* [14] occurs in monodomain Yb_4As_3 as well [8]. The hysteretic behavior indicates a metastable state when $B > 0$. To further study this effect, we recorded the time (t) dependence of the resistivity at 2 K after applying 16.5 T with a rate of 0.25 T/min (figure 2b) as well as after reducing the field back to 0 T with the same rate (figure 2c). The observed relaxation cannot be fitted by a simple logarithmic decay. Even 10 h after switching off the field, no saturation occurs and as shown in figure 2c, the resistivity is still far from its value at the beginning of the measurements. The 30 T and 58 T pulsed-field experiments revealed that an increase of the maximum field increases the hysteresis between the $\rho(B)$ curves (figure 6a). Upon increasing the temperature, the relaxation effect becomes gradually suppressed: figure 3 displays $\rho(t)$ in 16.5 T at various temperatures. The amplitude of the relaxation decreases with increasing T and vanishes for $T \geq 7$ K. Following Aoki *et al* [14] we tried to fit our $\rho(t)$ data with the sum of two exponential decays, which works satisfactorily well above 2 K, but only very approximately at lower temperatures. The obtained two time constants τ_1 and τ_2 decrease continuously upon warming (inset of figure 3). A more precise determination for τ_2 below about 2 K would require collection of data of $\rho(t)$ for more than 10 h.

The observed relaxation and hysteresis might possibly indicate a slow thermally activated domain motion [15], i.e. either (i) the motion of chain domains related to the domain structure of our polydomain samples or (ii) the motion of magnetic domains related to the SG behavior below 0.15 K [8]. A motion of chain domains would result in a pronounced relaxation in the magnetization, too, because the low- T susceptibility is strongly anisotropic [16]. However, as shown in figure 4, neither hysteresis nor relaxation was found in the dc-magnetization of polydomain Yb_4As_3 . On the other hand, a motion of SG domains is unlikely, because the effect occurs well above T_{SG} and in very large magnetic fields (i.e. up to 58 T).

Another possibility is that the unusual relaxation is related to the slightly incomplete CO, being dynamic in nature (electron hopping via As-4p states between Yb^{3+}

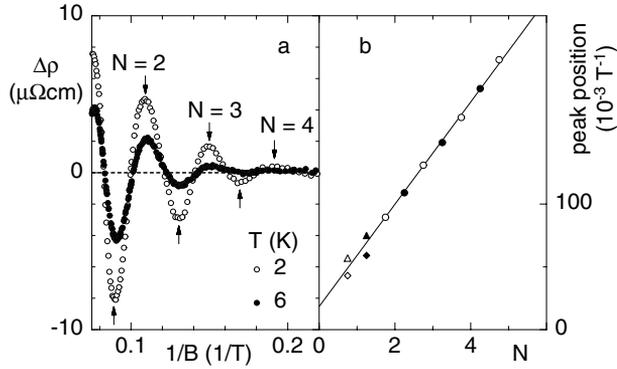


Figure 5. (a) Shubnikov–de Haas oscillations for magnetic fields applied parallel to the $\langle 110 \rangle$ direction of polydomain Yb_4As_3 obtained from $\rho(B)$ measurements in decreasing field at different temperatures. Arrows indicate maxima and minima. (b) ‘Landau plot’ of SdH maxima (filled symbols, x -position shifted by $+0.25$) and minima (open symbols, x -position shifted by -0.25). The straight line has a slope of $40 \times 10^{-3} \text{ T}^{-1}$, corresponding to a SdH frequency of 25 T.

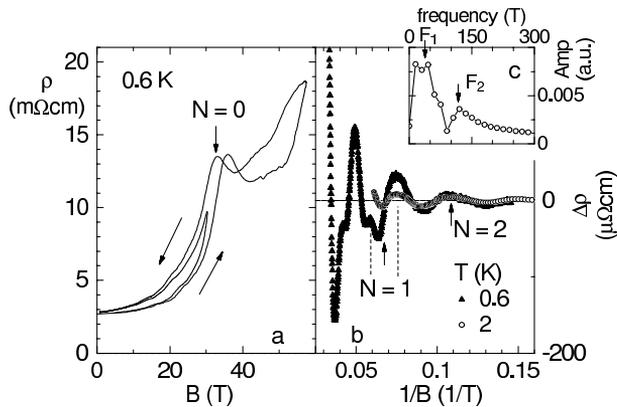


Figure 6. Pulsed-field resistivity $\rho(B)$ of Yb_4As_3 measured at 0.6 K along the $\langle 110 \rangle$ direction of polydomain Yb_4As_3 (a). SdH oscillations obtained from the 30 T pulse in decreasing field shown in (a), compared with SdH data shown in figure 5a (b). Vertical arrows in (a) and (b) indicate calculated positions of SdH maxima, dotted lines in (b) mark spin splitting of $N = 1$ maximum. Fast-Fourier transformation of 30 T pulse data (c). Arrows indicate two characteristic frequencies $F_1 = 40 \text{ T}$ and $F_2 = 115 \text{ T}$.

and Yb^{2+} nearest-neighbor sites on different space diagonals). Most interestingly, no hysteresis and relaxation occurs in the resistivity of the doped, but charge-ordered system $\text{Yb}_4(\text{As}_{0.96}\text{Sb}_{0.06})_3$. The latter is also lacking the low- T increase in $\rho(T)$ (figure 1b).

5. Shubnikov–de Haas oscillations

In the following we analyze the isothermal resistivity which shows SdH oscillations which have also been recently observed by Aoki *et al* [14]. The analysis is complicated by the hysteresis and relaxation effects discussed in the previous section. Only for measurements taken in decreasing field, the positions of the SdH oscillations could be determined consistently for all temperatures up to 7 K. To analyze the SdH frequency we used the field range $4.5 \text{ T} \leq B \leq 12.5 \text{ T}$ (figure 5a). As shown in figure 5b, the oscillations result from the depopulation of the Landau tubes $N = 4, 3$ and 2 . A SdH frequency F of 25 T is determined, in agreement with ref. [14]. This, most likely, arises from the As-4*p* holes, since their mobility is much higher than that of the Yb-4*f* electrons. Assuming one pair of almost degenerate As-4*p* bands as derived from LSDA + U band-structure calculations [12], F would correspond to a carrier concentration of $n \approx 1.4 \times 10^{18} \text{ cm}^{-3}$. This value is about two times smaller than $(eR_{\text{H}})^{-1} \approx 3 \times 10^{18} \text{ cm}^{-3}$, determined for the same single crystal, though applying a *one-band* model.

In a previous work [8], the observation of two characteristic frequencies $F_1 = (40 \pm 10) \text{ T}$ and $F_2 = (112 \pm 5) \text{ T}$ has been reported. In these measurements, which were performed under uniaxial pressure along the cubic $\langle 111 \rangle$ direction in order to induce a monodomain low- T state, a sample with much larger cross section had to be used. Therefore, the sensitivity was much lower than that in the measurements reported here. In [8], SdH oscillations had been visible only in the field interval $10 \text{ T} \leq B \leq 18.8 \text{ T}$. In this field range, however, as shown in figure 6, additional oscillations occur which now can be attributed to spin-splitting effects: due to the low-carrier concentration, the system is already in its quantum limit. Assuming a splitting $v_s = 0.016 \text{ T}^{-1}$ of the $N = 1$ maximum (see dotted lines in figure 6b, a very similar value was found also in [14]), the effective Landé g -factor for the As-4*p* holes given by $g_{\text{eff}} = 2Fv_s / (m_{\text{eff}}/m_0)$, is calculated to be 2.9 ± 0.2 . Here, we used the value for the effective carrier mass, $m_{\text{eff}} = (0.275 \pm 0.005)m_0$, determined from the analysis of the T -dependence of the SdH oscillations in *low* fields $4.5 \text{ T} \leq B \leq 11 \text{ T}$, discussed below. A fast-Fourier transformation of the data up to 30 T reveals a very similar spectrum as found in the early experiment on the monodomain sample [8] which proves that, (i) there is no significant difference between the measurements on polydomain Yb_4As_3 for $B \parallel \langle 110 \rangle$ and monodomain Yb_4As_3 for $B \parallel \langle 111 \rangle$, in agreement with the predicted almost spherical As-4*p* hole Fermi surface [12] and that (ii) the frequencies F_1 and F_2 do not represent the true SdH frequency, but are caused most likely by spin-splitting effects.

To determine the effective carrier mass related to the SdH frequency of 25 T, we used the T dependence of the SdH oscillations related to $N=4$ and $N=34$, i.e., those detected below 10 T. At higher magnetic fields, the observed T dependence of the SdH oscillations could not be described well using the standard Lifshitz–Kosevich (LK) theory. This is caused by both the spin-splitting effects discussed above and the already discussed unusual hysteresis effects that strongly increase in size at higher B and lower T . Therefore, we have excluded measurements taken below 2 K from the mass analysis, too. As shown in figure 7a, the T dependence of the SdH oscillations can be well-fitted by the LK theory. The resulting effective carrier mass, $m_{\text{eff}} = (0.275 \pm 0.005)m_0$, is smaller than that ($0.4m_0$) obtained by Aoki *et al* [14] from their analysis for SdH oscillations below 2 K. Most interestingly, both these values are substantially smaller than that of the cyclotron-resonance (CR) mass, $m_{\text{CR}} = 0.72m_0$ [17]. This is opposed to Kohn’s theorem for electron motion in a Galilean invariant electron gas [18], according to which m_{CR} , originating from the center of mass

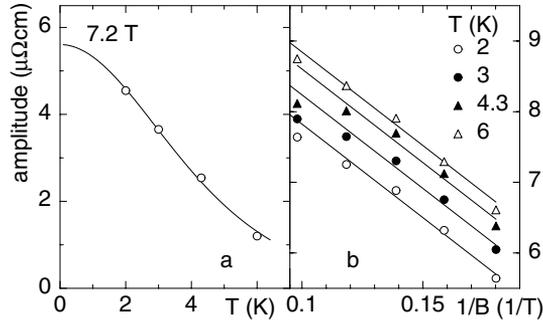


Figure 7. (a) T -dependence of the SdH oscillations at 7.2 T (symbols) and a fit to the standard Lifshitz and Kosevich theory (solid line). (b) Dingle-plot of $\log(\text{amplitude} \cdot B^{1/2} \cdot \sinh(14.69 \text{ T/K} \cdot m^*/m_0 \cdot T/B))$ vs. $1/B$. From the slope of the solid lines a Dingle temperature of $T_D = 6.6$ K is estimated.

motion of the electron system in a magnetic field, must be smaller than m_{eff} , since only the latter is affected also by electron–electron interactions. A similar violation of Kohn’s theorem has been observed in the rare-earth monopnictides GdAs [19] and LaSb [20]. For both of these semimetallic systems, m_{CR} was found to be twice as large as the de Haas–van Alphen derived m_{eff} . As shown in a theoretical study of the cyclotron resonance by Kanki and Yamada [21], Umklapp processes may reduce the resonance frequency of non-interacting electrons leading to an *increase* in m_{CR} . According to their theory, Kohn’s theorem is not necessarily valid for strongly correlated electron systems.

As shown in figure 7b, the analysis of the field dependence of the oscillations below 8.5 T taken at differing temperatures reveals a Dingle temperature of $T_D = 6.6$ K, corresponding to a charge-carrier mean-free path of $\ell \approx 215$ Å. We note that the magnon mean-free path along the $S = 1/2$ chains determined from the $B = 0$ thermal conductivity, is roughly 500 Å [9], and that both values are much smaller than the domain size of approximately 1 μm .

6. Summary

The transport properties of the low-carrier density 1D $S = 1/2$ antiferromagnet Yb_4As_3 , arising from its 3D semimetallic electronic band structure, were investigated down to very low temperatures ($T \geq 20$ mK) and up to very high magnetic fields ($B \leq 60$ T). The ‘HF’-like resistivity observed even in high magnetic fields where the large $B = 0$ in- T linear specific heat is suppressed, suggests a two-band model of current-carrying As-derived $4p$ -holes scattered by heavy Yb-derived $4f$ -electrons. An unusual hysteresis was observed in the isothermal magnetoresistance indicating a metastable state when $B > 0$. A very slow relaxation of the resistivity could be detected for temperatures below 7 K. This effect can neither be related to chain-domain motion nor to SG domain motion, but seems to rather point to the slow motion of point defects due to the dynamic nature of the CO state. A detailed analysis of the isothermal resistivity reveals SdH oscillations with a very low frequency of 25 T which confirm the existence of a small concentration of light As- $4p$

holes. The effective carrier mass is estimated to be $m_{\text{eff}} = (0.275 \pm 0.005)m_0$, a value more than two times smaller than the observed CR mass $m_{\text{CR}} = 0.72m_0$ [17].

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